

DATASHEET

Description

The 9DBU0731 is a member of IDT's 1.5V Ultra-Low-Power (ULP) PCle family. The device has 7 output enables for clock management, and 3 selectable SMBus addresses.

Recommended Application

1.5V PCIe Gen1-2-3 Fanout Buffer (FOB)

Output Features

• 7 - 1-167MHz Low-Power (LP) HCSL DIF pairs

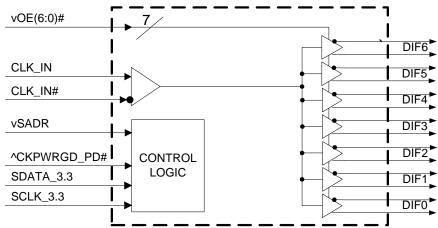
Key Specifications

- DIF additive cycle-to-cycle jitter < 5ps
- DIF output-to-output skew < 60ps
- DIF additive phase jitter is < 300fs rms for PCle Gen3
- DIF additive phase jitter < 350s rms for SGMII

Features/Benefits

- LP-HCSL outputs; save 14 resistors compared to standard HCSL outputs
- 36mW typical power consumption; eliminates thermal concerns
- Outputs can optionally be supplied from any voltage between 1.05V and 1.5V; maximum power savings
- Spread Spectrum (SS) compatible; allows SS for EMI reduction
- OE# pins for each output; support DIF power management
- HCSL-compatible differential input; can be driven by common clock sources
- SMBus-selectable features; optimize signal integrity to application
 - slew rate for each output
 - differential output amplitude
- Device contains default configuration; SMBus interface not required for device operation
- 3.3V tolerant SMBus interface works with legacy controllers
- Three selectable SMBus addresses; multiple devices can easily share an SMBus segment
- 5 x 5 mm 40-VFQFPN package; minimal board space

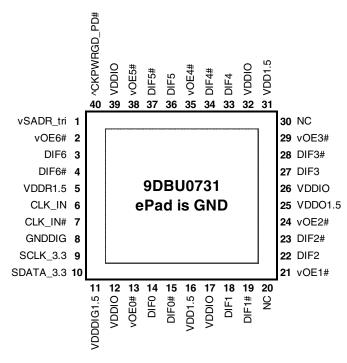
Block Diagram



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Pin Configuration



40-VFQFPN, 5mm x 5mm 0.4mm pin pitch

^prefix indicates internal Pull-Up Resistor v prefix indicates Internal Pull-Down Resistor

SMBus Address Selection Table

	SADR	Address	+ Read/Write bit
State of SADR on first application of	0	1101011	X
CKPWRGD_PD#	M	1101100	X
	1	1101101	x

Power Management Table

CKPWRGD PD#	CLK IN	SMBus	OEx# Pin	D	lFx
CKI WKGD_I D#	OLK_III	OEx bit	OLX#1III	True O/P	Comp. O/P
0	Χ	X	X	Low	Low
1	Running	0	Х	Low	Low
1	Running	1	0	Running	Running
1	Running	1	1	Low	Low

Power Connections

Pin Number			Description
VDD	VDDIO	GND	Description
			Input
5		41	receiver
			analog
11		8	Digital Power
16,25,31	12,17,26,32, 39	41	DIF outputs,Logic

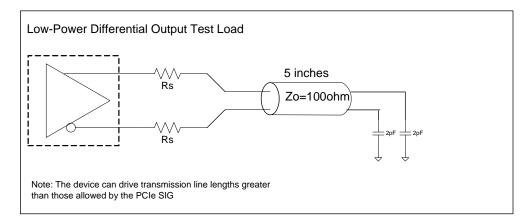


Pin Descriptions

PIN#	PIN NAME	PIN TYPE	DESCRIPTION
1	vSADR_tri	LATCHED IN	Tri-level latch to select SMBus Address. It has an internal 120kohm pull down resistor. See SMBus Address Selection Table.
2	vOE6#	IN	Active low input for enabling output 6. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs
3	DIF6	OUT	Differential true clock output
4	DIF6#	OUT	Differential Complementary clock output
5	VDDR1.5	PWR	1.5V power for differential input clock (receiver). This VDD should be treated as an Analog power rail and filtered appropriately.
6	CLK_IN	IN	True Input for differential reference clock.
	CLK_IN#	IN	Complementary Input for differential reference clock.
	GNDDIG	GND	Ground pin for digital circuitry
	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
	SDATA_3.3	1/0	Data pin for SMBus circuitry, 3.3V tolerant.
	VDDDIG1.5	PWR	1.5V digital power (dirty power)
	VDDIO VDDIO	PWR	Power supply for differential outputs
12	VDDIO	FVVII	Active low input for enabling output 0. This pin has an internal 120kohm pull-down.
13	vOE0#	IN	
1.1	DIFO	OUT	1 =disable outputs, 0 = enable outputs Differential true clock output
	DIF0	OUT	
	DIF0#	OUT	Differential Complementary clock output
	VDD1.5	PWR	Power supply, nominally 1.5V
	VDDIO	PWR	Power supply for differential outputs
	DIF1	OUT	Differential true clock output
	DIF1#	OUT	Differential Complementary clock output
20	NC	N/A	No Connection.
21	vOE1#	IN	Active low input for enabling output 1. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs
22	DIF2	OUT	Differential true clock output
23	DIF2#	OUT	Differential Complementary clock output
24	vOE2#	IN	Active low input for enabling output 2. This pin has an internal 120kohm pull-down. 1 = disable outputs, 0 = enable outputs
25	VDDO1.5	PWR	Power supply for outputs, nominally 1.5V.
	VDDIO	PWR	Power supply for differential outputs
	DIF3	OUT	Differential true clock output
	DIF3#	OUT	Differential Complementary clock output
			Active low input for enabling output 3. This pin has an internal 120kohm pull-down.
	vOE3#	IN	1 =disable outputs, 0 = enable outputs
	NC		No Connection.
	VDD1.5	PWR	Power supply, nominally 1.5V
32	VDDIO	PWR	Power supply for differential outputs
33	DIF4	OUT	Differential true clock output
34	DIF4#	OUT	Differential Complementary clock output
35	vOE4#	IN	Active low input for enabling output 4. This pin has an internal 120kohm pull-down. 1 =disable outputs, 0 = enable outputs
36	DIF5	OUT	Differential true clock output
37	DIF5#	OUT	Differential Complementary clock output
	vOE5#	IN	Active low input for enabling output 5. This pin has an internal 120kohm pull-down.
- 00	VDDIO	DWD	1 =disable outputs, 0 = enable outputs
39	VDDIO	PWR	Power supply for differential outputs
40	^CKPWRGD_PD#	IN	Input notifies device to sample latched inputs and start up on first high assertion. Low enters Power Down Mode, subsequent high assertions exit Power Down Mode. This pin has internal
			120kohm pull-up resistor.
41	EPAD	GND	Connect paddle to ground.



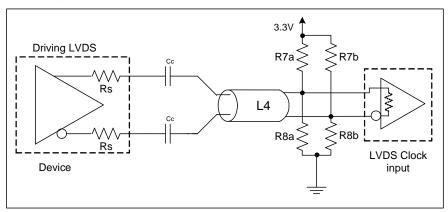
Test Loads



Alternate Differential Output Terminations

Rs	Zo	Units
33	100	Ohms
27	85	Oillis

Driving LVDS



Driving LVDS inputs

	,		
	Receiver has Receiver does not		
Component	termination	have termination	Note
R7a, R7b	10K ohm	140 ohm	
R8a, R8b	5.6K ohm	75 ohm	
Cc	0.1 uF	0.1 uF	
Vcm	1.2 volts	1.2 volts	



Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9DBU0731. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Supply Voltage	VDDx	Applies to VDD, VDDA and VDDIO	-0.5		2	V	1,2
Input Voltage	V_{IN}		-0.5		V _{DD} +0.5	V	1,
Input High Voltage, SMBus	V_{IHSMB}	SMBus clock and data pins			3.3	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Clock Input Parameters

TA = T_{AMB}. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

T = TAINIB, Supply Tolkages per Herman Speraktern Containence, Coo Took Education Containence								
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES	
Input Common Mode Voltage - DIF_IN	V_{COM}	Common Mode Input Voltage	200		725	mV	1	
Input Swing - DIF_IN	V_{SWING}	Differential value	300		1450	mV	1	
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2	
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA		
Input Duty Cycle	d_{tin}	Measurement from differential wavefrom	45	50	55	%	1	
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		150	ps	1	

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

³ Not to exceed 2.0V.

² Slew rate measured through +/-75mV window centered around differential zero



Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMITO	NOTES
							NOTES
Supply Voltage	VDDx	Supply voltage for core and analog	1.425	1.5	1.575	V	
Output Supply Voltage	VDDIO	Low Voltage Supply LP-HCSL Outputs	0.95	1.05-1.5	1.575	V	
Ambient Operating	T_{AMB}	Commmercial range	0	25	70	°C	1
Temperature		Industrial range	-40	25	85	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus	0.75 V _{DD}		$V_{DD} + 0.3$	V	
Input Mid Voltage	V_{IM}	Single-ended tri-level inputs ('_tri' suffix)	$0.4~V_{DD}$		$0.6 V_{DD}$	V	
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus	-0.3		0.25 V _{DD}	V	
	I_{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	
Input Current		Single-ended inputs					
input Current	I_{INP}	$V_{IN} = 0 \text{ V}$; Inputs with internal pull-up resistors	-200		200	uA	
		V _{IN} = VDD; Inputs with internal pull-down resistors					
Input Frequency	F _{in}		1		167	MHz	2
Pin Inductance	L_{pin}				7	nΗ	1
	C _{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,5
	C _{OUT}	Output pin capacitance			6	pF	1
Oll Orabili alia		From V _{DD} Power-Up and after input clock			4		4.0
Clk Stabilization	T_{STAB}	stabilization or de-assertion of PD# to 1st clock			1	ms	1,2
Input SS Modulation	f	Allowable Frequency for PCIe Applications	30		33	kHz	
Frequency PCIe	f _{MODINPCle}	(Triangular Modulation)	30		33	KIIZ	
Input SS Modulation	f _{MODIN}	Allowable Frequency for non-PCIe Applications	0		66	kHz	
Frequency non-PCle	MODIN	(Triangular Modulation)	0		00	KIIZ	
OE# Latency	t _{LATOE#}	DIF start after OE# assertion	1		3	clocks	1,3
2 =	*LATOE#	DIF stop after OE# deassertion				0.00.10	.,0
Tdrive_PD#	t _{DRVPD}	DIF output enable after			300	us	1,3
		PD# de-assertion			_		
Tfall	t _F	Fall time of single-ended control inputs			5	ns	2
Trise	t _R	Rise time of single-ended control inputs			5	ns	2
SMBus Input Low Voltage	V _{ILSMB}				0.6	V	
SMBus Input High Voltage	V _{IHSMB}	$V_{DDSMB} = 3.3V$, see note 4 for $V_{DDSMB} < 3.3V$	2.1		3.3	V	4
SMBus Output Low Voltage	V_{OLSMB}	@ I _{PULLUP}			0.4	V	
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	
Nominal Bus Voltage	V_{DDSMB}	Bus Voltage	1.425		3.3	V	
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			400	kHz	6
10							

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

 $^{^4}$ For $V_{\text{DDSMB}} < 3.3 V, \ V_{\text{IHSMB}} >= 0.8 x V_{\text{DDSMB}}$

⁵DIF_IN input



Electrical Characteristics-DIF Low-Power HCSL Outputs

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

AMD) I-I-)3						_	
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	dV/dt	Scope averaging on, fast setting	1.4	2.3	3.5	V/ns	1,2,3
Siew fate	dV/dt	Scope averaging on, slow setting	0.9	1.5	2.5	V/ns	1,2,3
Slew rate matching	∆dV/dt	Slew rate matching, Scope averaging on		9.3	20	%	1,2,4
Voltage High	V _{HIGH}	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	630	750	850	mV	7
Voltage Low	V_{LOW}	averaging on)	-150	26	150	""	7
Max Voltage	Vmax	Measurement on single ended signal using		763	1150	mV	7
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	22		IIIV	7
Vswing	Vswing	Scope averaging off	300	1448		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250	390	550	mV	1,5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off		11	140	mV	1,6

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Current Consumption

 $TA = T_{AMB}$; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DDA}	VDDA+VDDR, @100MHz		2.2	3	mA	
	I _{DD}	VDD, All outputs active @100MHz		3.6	5	mA	
	I _{DDIO}	VDDIO, All outputs active @100MHz		26	31	mA	
.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	I _{DDAPD}	VDDA+VDDR, CKPWRGD_PD#=0		0.4	1	mA	2
	I _{DDPD}	VDDx, CKPWRGD_PD#=0		0.25	0.6	mA	2
	I _{DDIOPD}	VDDIO, CKPWRGD_PD#=0		0.0006	0.1	mA	2

¹ Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

⁷ At default SMBus settings.

² Input clock stopped.



Electrical Characteristics-Output Duty Cycle, Jitter, Skew and PLL Characteristics

TA = T_{AMB}; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle Distortion	t _{DCD}	Measured differentially, @100MHz	-1	-0.2	0.5	%	1,3
Skew, Input to Output	t _{pdBYP}	Bypass Mode, $V_T = 50\%$	2400	2862	3700	ps	1
Skew, Output to Output	t _{sk3}	V _T = 50%		30	60	ps	1,4
Jitter, Cycle to cycle	t _{jcy c-cy c}	Additive Jitter in Bypass Mode		0.1	5	ps	1,2

¹ Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Phase Jitter Parameters

 $TA = T_{AMB}$; Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

						INDUSTRY		
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	LIMIT	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		0.1	5	N/A	ps (p-p)	1,2,3,5
		PCIe Gen 2 Lo Band		0.1	0.4	N/A	ps	1,2,3,4,
		10kHz < f < 1.5MHz		0.1	0.4	IN/A	(rms)	5
	t _{jphPCleG2}	PCIe Gen 2 High Band		0.1	0.7	N/A	ps	1,2,3,4
		1.5MHz < f < Nyquist (50MHz)		0.1	0.7	IN/A	(rms)	1,2,3,4
Additive Phase Jitter,	t	PCIe Gen 3		0.1	0.3	N/A	ps	1,2,3,4
Bypass Mode	t _{jphPCleG3}	(PLL BW of 2-4MHz, CDR = 10MHz)		0.1	0.5	IN/A	(rms)	1,2,3,4
Буразз Моче		125MHz, 1.5MHz to 10MHz, -20dB/decade					fs	
	t _{jphSGMIIM0}	rollover < 1.5MHz, -40db/decade rolloff >		200	250	N/A	(rms)	1,6
		10MHz					(11113)	
		125MHz, 12kHz to 20MHz, -20dB/decade					fs	
	t _{iphSGMIIM1}	rollover < 1.5MHz, -40db/decade rolloff >		313	350	N/A	(rms)	1,6
		10MHz					(11115)	

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode.

⁴ All outputs at default slew rate

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

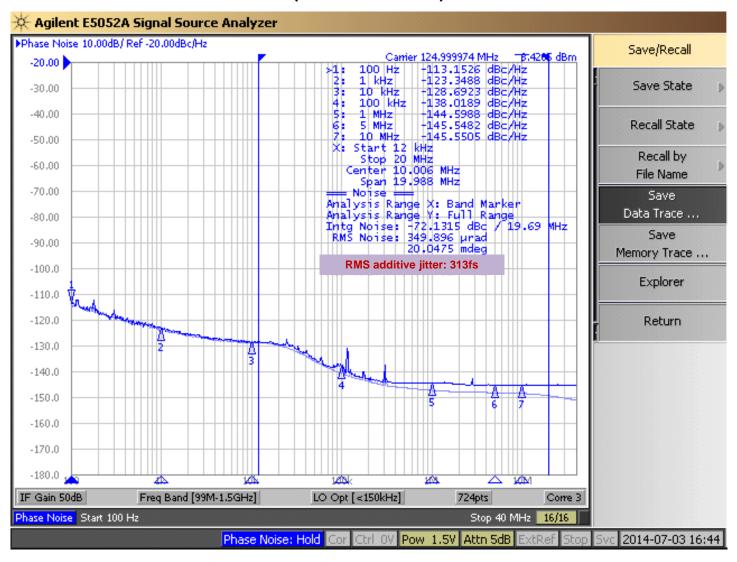
⁴ For RMS figures, additive jitter is calculated by solving the following equation: Additive jitter = SQRT[(total jitter)^2 - (input jitter)^2]

⁵ Driven by 9FGV0831 or equivalent

⁶ Rohde&Schwarz SMA100



Additive Phase Jitter Plot: 125M (12kHz to 20MHz)





General SMBus Serial Interface Information

How to Write

- Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Block Write Operation						
Controll	er (Host)		IDT (Slave/Receiver)				
Т	starT bit						
Slave A	Address						
WR	WRite						
			ACK				
Beginning	Byte = N						
			ACK				
Data Byte	Count = X						
			ACK				
Beginnin	g Byte N						
			ACK				
0		×					
0		X Byte	0				
0		Ö	0				
			0				
Byte N	+ X - 1						
			ACK				
Р	stoP bit						

Note: SMBus Address is Latched on SADR pin.

How to Read

- Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) will send a separate start bit
- Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- · Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- Controller (host) will send a stop bit

	Index Block F	peration	
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
	•		Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ē	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



SMBus Table: Output Enable Register ¹

Byte 0	Name	Control Function	Туре	0	1	Default
Bit 7	DIF OE5	Output Enable	RW	Low/Low	Enabled	1
Bit 6	DIF OE4	Output Enable	RW	Low/Low	Enabled	1
Bit 5		Reserved				1
Bit 4	DIF OE3	Output Enable	RW	Low/Low	Enabled	1
Bit 3	DIF OE2	Output Enable	RW	Low/Low	Enabled	1
Bit 2	DIF OE1	Output Enable	RW	Low/Low	Enabled	1
Bit 1		Reserved				1
Bit 0	DIF OE0	Output Enable	Output Enable RW Low/Low Enabled		Enabled	1

^{1.} A low on these bits will overide the OE# pin and force the differential output Low/Low

SMBus Table: PLL Operating Mode and Output Amplitude Control Register

Byte 1	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				0
Bit 6		Reserved				1
Bit 5	DIF OE6	Output Enable	RW	Low/Low	Enabled	1
Bit 4		Reserved				0
Bit 3		Reserved				1
Bit 2	Reserved					1
Bit 1	AMPLITUDE 1	Controls Output Amplitude RW 00 = 0.55V 01= 0.65V				1
Bit 0	AMPLITUDE 0	Controls Output Amplitude	RW	10 = 0.7V	11 = 0.8V	0

^{1.} A low on the DIF OE bit will overide the OE# pin and force the differential output Low/Low

SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default
Bit 7	SLEWRATESEL DIF5	Adjust Slew Rate of DIF5	RW	Slow Setting	Fast Setting	1
Bit 6	SLEWRATESEL DIF4	Adjust Slew Rate of DIF4	RW	Slow Setting	Fast Setting	1
Bit 5		Reserved				1
Bit 4	SLEWRATESEL DIF3	Adjust Slew Rate of DIF3	RW	Slow Setting	Fast Setting	1
Bit 3	SLEWRATESEL DIF2	Adjust Slew Rate of DIF2	RW	Slow Setting	Fast Setting	1
Bit 2	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	Slow Setting	Fast Setting	1
Bit 1		Reserved				1
Bit 0	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	Slow Setting	Fast Setting	1

Note: See "DIF 0.7V Low-Power HCSL Outputs" table for slew rates.

SMBus Table: DIF Slew Rate Control Register

Byte 3	Name	Control Function	Туре	0	1	Default	
Bit 7		Reserved				1	
Bit 6		Reserved				1	
Bit 5		Reserved				0	
Bit 4		Reserved				0	
Bit 3		Reserved				0	
Bit 2		Reserved					
Bit 1	Reserved						
Bit 0	SLEWRATESEL DIF6	Adjust Slew Rate of DIF6	RW	Slow Setting	Fast Setting	1	

Note: See "DIF 0.7V Low-Power HCSL Outputs" table for slew rates.

Byte 4 is Reserved and reads back 'hFF



SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R			0
Bit 6	RID2	Revision ID	R	A rev = 0000		0
Bit 5	RID1	Revision ID	R	A rev = 0000	0	
Bit 4	RID0		R			0
Bit 3	VID3		R			0
Bit 2	VID2	VENDOR ID	R	0001 = IDT		0
Bit 1	VID1	VENDOR ID	R			0
Bit 0	VID0		R			1

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGx,	01 = DBx,	1
Bit 6	Device Type0	Device Type	R	10 = DMx, 11=	= DBx w/oPLL	1
Bit 5	Device ID5		R			0
Bit 4	Device ID4		R			0
Bit 3	Device ID3	Device ID	R	000111 bina	ny or 07 hey	0
Bit 2	Device ID2	Device iD	R	000111 billa	iy or or nex	1
Bit 1	Device ID1		R			1
Bit 0	Device ID0]	R			1

SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Туре	0	1	Default
Bit 7		Reserved				0
Bit 6		Reserved				0
Bit 5		Reserved				0
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist		
Bit 2	BC2	Byte Count Programming	RW	many bytes will be r	ead back, default is	0
Bit 1	BC1		RW	= 8 b	ytes.	0
Bit 0	BC0		RW			0



Marking Diagrams

ICS
DBU0731AL
YYWW
COO
LOT



Notes:

- 1. "LOT" is the lot sequence number.
- 2. "COO" denotes country of origin.
- 3. YYWW is the last two digits of the year and week that the part was assembled.
- 4. Line 2: truncated part number
- 5. "L" denotes RoHS compliant package.
- 6. "I" denotes industrial temperature range device.

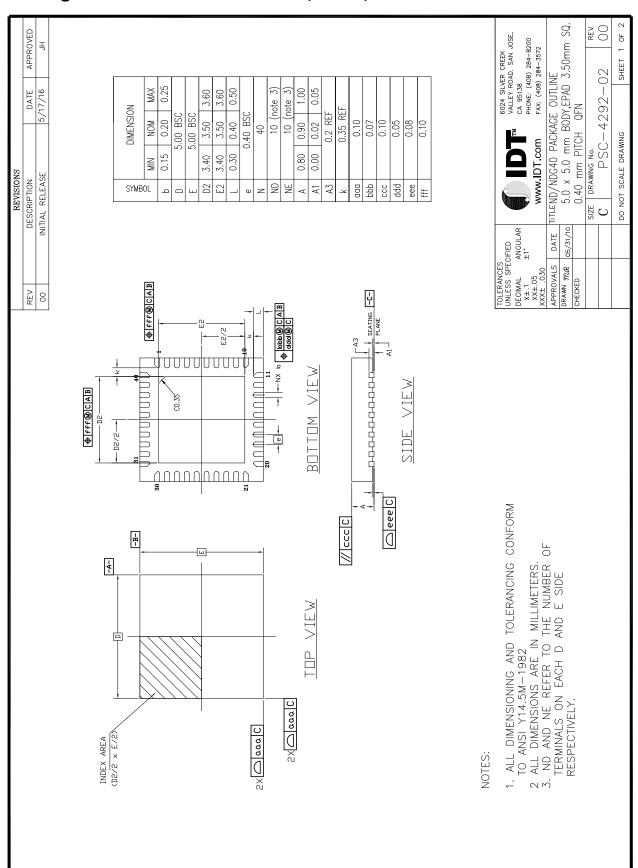
Thermal Characteristics

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	θ_{JC}	Junction to Case		42	°C/W	1
	θ_{Jb}	Junction to Base		2.4	°C/W	1
Thermal Resistance	θ_{JA0}	Junction to Air, still air	NDG40	39	°C/W	1
Thermal nesistance	θ_{JA1}	Junction to Air, 1 m/s air flow	NDG40	33	°C/W	1
	θ_{JA3}	Junction to Air, 3 m/s air flow		28	°C/W	1
	θ_{JA5}	Junction to Air, 5 m/s air flow		27	°C/W	1

¹ePad soldered to board

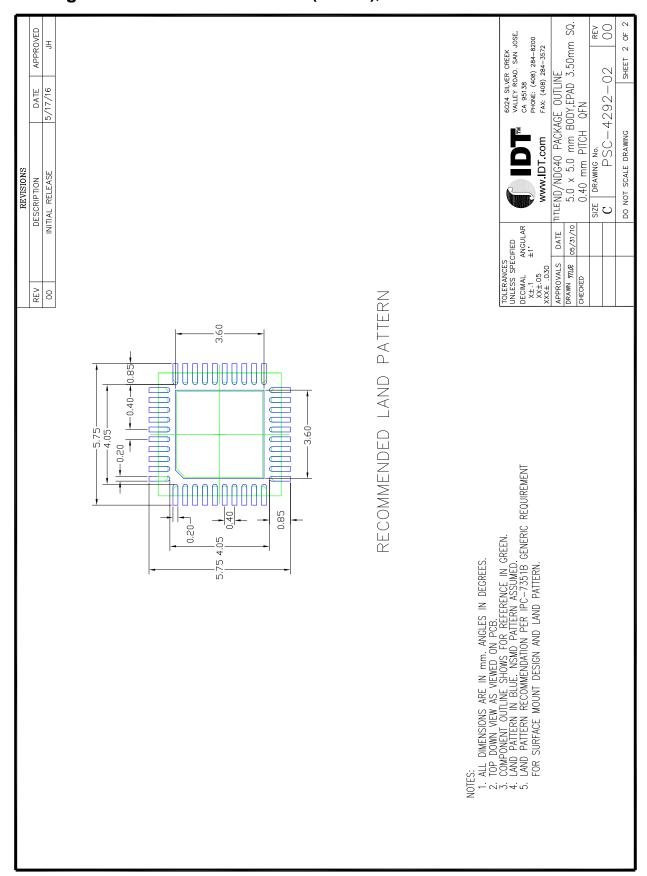


Package Outline and Dimensions (NDG40)





Package Outline and Dimensions (NDG40), cont.





Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
9DBU0731AKLF	Trays	40-pin VFQFPN	0 to +70° C
9DBU0731AKLFT	Tape and Reel	40-pin VFQFPN	0 to +70° C
9DBU0731AKILF	Trays	40-pin VFQFPN	-40 to +85° C
9DBU0731AKILFT	Tape and Reel	40-pin VFQFPN	-40 to +85° C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History

Rev.	Initiator	Issue Date	Description	Page #
Α	RDW	7/16/2014	Updated electrical tables to final, and release	Various
В	RDW	9/19/2014	Updated SMBus Input High/Low parameters conditions, MAX values, and footnotes.	6
С	RDW	4/17/2015	 Updated pin out and pin descriptions to show ePad on package connected to ground. Minor updates to front page text for family consistency. Updated Clock Input Parameters table to be consistent with PCIe Vswing parameter. 	1-5
D	RDW	2/16/2017	1. Updated pin 25 from VDDA1.5 to VDDO1.5 to clearly indicate that this part has no PLL.	2-3

[&]quot;A" is the device revision designator (will not correlate with the datasheet revision).



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